



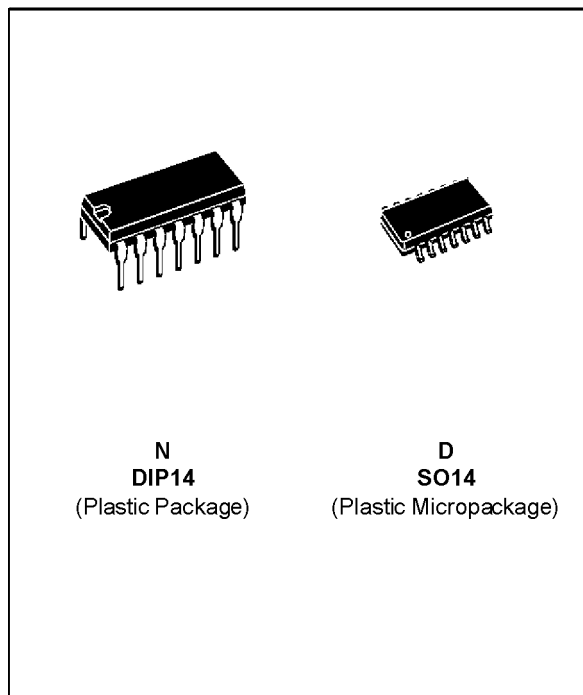
LOW POWER QUAD VOLTAGE COMPARATORS

- WIDE SINGLE SUPPLY VOLTAGE RANGE OR DUAL SUPPLIES FOR ALL DEVICES : +2V TO +36V OR $\pm 1V$ TO $\pm 18V$
- VERY LOW SUPPLY CURRENT (1.1mA) INDEPENDENT OF SUPPLY VOLTAGE (1.4mW/comparator at +5V)
- LOW INPUT BIAS CURRENT : 25nA TYP
- LOW INPUT OFFSET CURRENT : $\pm 5nA$ TYP
- INPUT COMMON-MODE VOLTAGE RANGE INCLUDES GROUND
- LOW OUTPUT SATURATION VOLTAGE : 250mV TYP. ($I_o = 4mA$)
- DIFFERENTIAL INPUT VOLTAGE RANGE EQUAL TO THE SUPPLY VOLTAGE
- TTL, DTL, ECL, MOS, CMOS COMPATIBLE OUTPUTS

DESCRIPTION

This device consists of four independent precision voltage comparators. All these comparators were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible.

These comparators also have a unique characteristic in the fact that the input common-mode voltage range includes ground even though operated from a single power supply voltage.

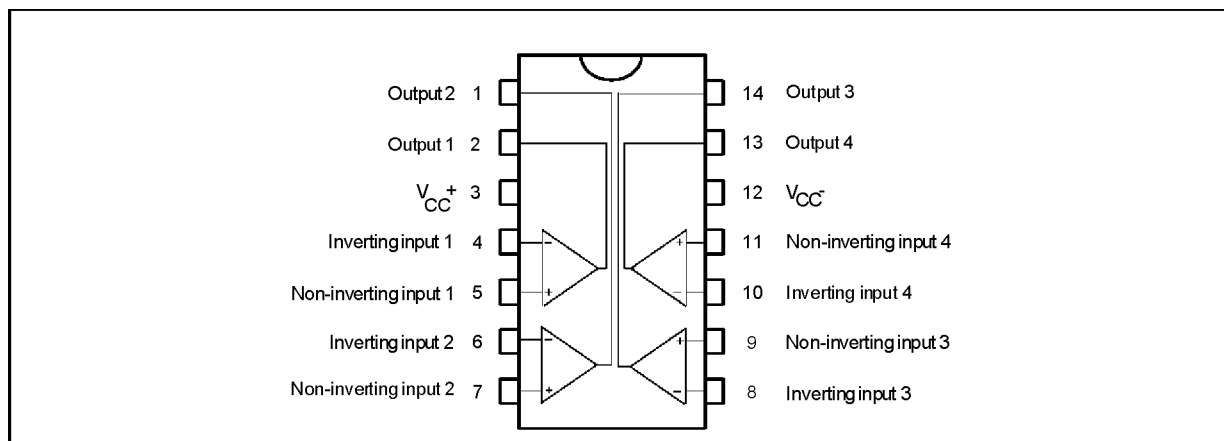


ORDER CODES

Part Number	Temperature Range	Package	
		N	D
LM2901	-40, +125°C	•	•
Example : LM2901D			

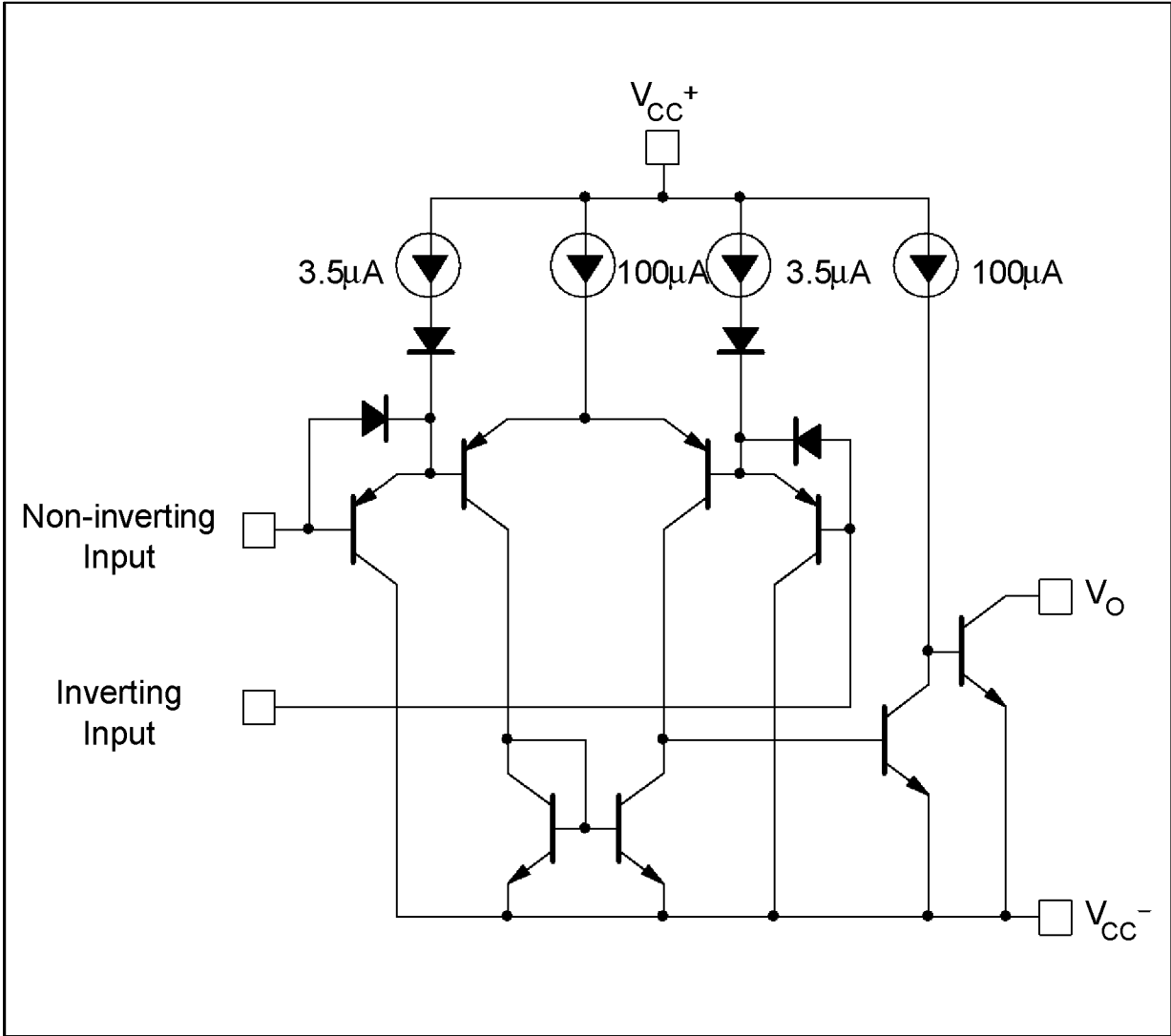
2901-01 TBL

PIN CONNECTIONS (top view)



2901-01 EPS

SCHEMATIC DIAGRAM (1/4 LM901)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	± 18 to 36	V
V_{id}	Differential Input Voltage	± 36	V
V_I	Input Voltage	-0.3 to $+36$	V
	Output Short-circuit to Ground - (note 1)	Infinite	
P_{tot}	Power Dissipation	570	mW
T_{oper}	Operating Free-air Temperature Range	-40 , $+125$	$^{\circ}C$
T_{stg}	Storage Temperature Range	-65 , $+150$	$^{\circ}C$

Notes : 1. Short-circuit from the output to V_{CC}^+ can cause excessive heating and eventual destruction. The maximum output current is approximately $20mA$, independent of the magnitude of V_{CC}^+ .

ELECTRICAL CHARACTERISTICS

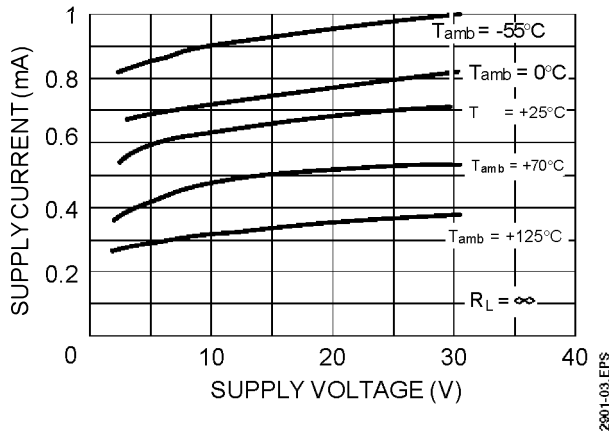
$V_{CC}^+ = +5V$, $V_{CC}^- = GND$, $T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage – (note 2) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	7 15	mV
I_{io}	Input Offset Current $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		5	50 150	nA
I_{ib}	Input Bias Current (I_{i^+} or I_{i^-}) - (note 3) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		25	250 400	nA
A_{vd}	Large Signal Voltage Gain ($V_{CC} = 15V$, $R_L = 15k\Omega$, $V_O = 1$ to $11V$)	25	200		V/mV
I_{CC}	Supply Current (all comparators) $V_{CC} = +5V$, no load $V_{CC} = +30V$, no load		1.1 1.3	2 2.5	mA
V_{icm}	Input Common Mode Voltage Range - (note 4) ($V_{CC} = 30V$) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	0 0		$V_{CC}^+ - 1.5$ $V_{CC}^+ - 2$	V
V_{id}	Differential Input Voltage - (note 6)			V_{CC}^+	V
V_{OL}	Low Level Output Voltage ($V_{id} = -1V$, $I_{sink} = 4mA$) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		250	400 700	mV
I_{OH}	High Level Output Current ($V_{id} = 1V$) ($V_{CC} = V_O = 30V$) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		0.1	1	nA μA
I_{sink}	Output Sink Current ($V_{id} = -1V$, $V_O = 1.5V$)	6	16		mA
t_{re}	Response Time – (note 5) ($R_L = 5.1k\Omega$ connected to V_{CC}^+)		1.3		μs

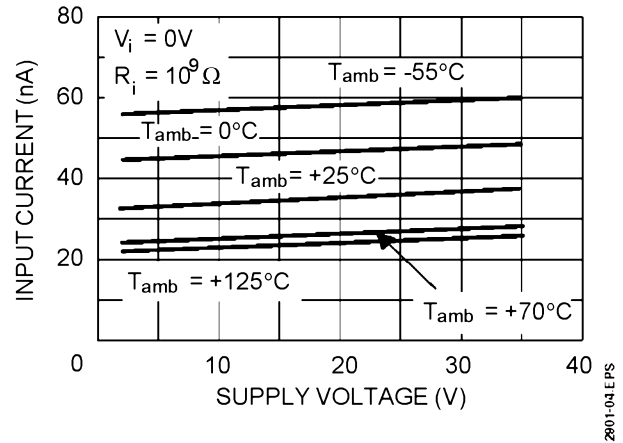
- Notes :**
2. At output switch point, $V_O \approx 1.4V$, $R_S = 0$ with V_{CC}^+ from 5V to 30V, and over the full input common-mode range (0V to $V_{CC}^+ - 1.5V$).
 3. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output, so no loading charge exists on the reference of input lines.
 4. The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is $V_{CC}^+ - 1.5V$, but either or both inputs can go to +30V without damage.
 5. The response time specified is for a 100mV input step with 5mV overdrive. For larger overdrive signals 300ns can be obtained.
 6. Positive excursions of input voltage may exceed the power supply level. As long as the other voltage remains within the common-mode range, the comparator will provide a proper output state. The low input voltage state must not be less than $-0.3V$ (or 0.3V below the negative power supply, if used).

2901-03.TBL

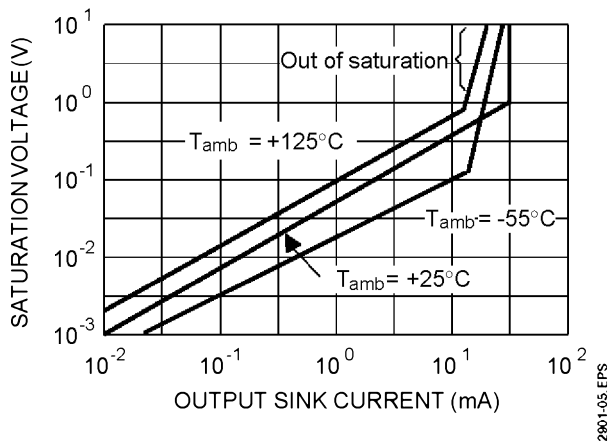
SUPPLY CURRENT versus
SUPPLY VOLTAGE



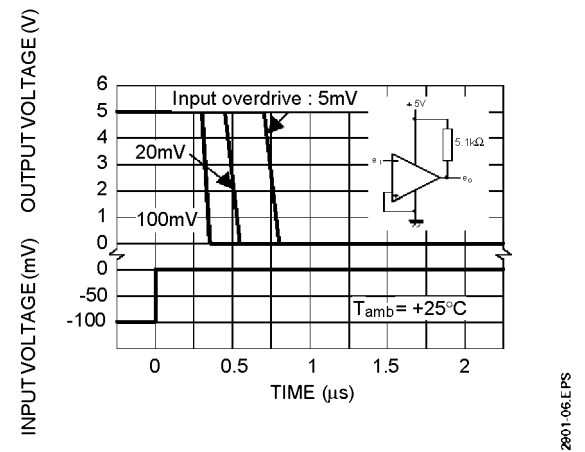
INPUT CURRENT versus
SUPPLY VOLTAGE



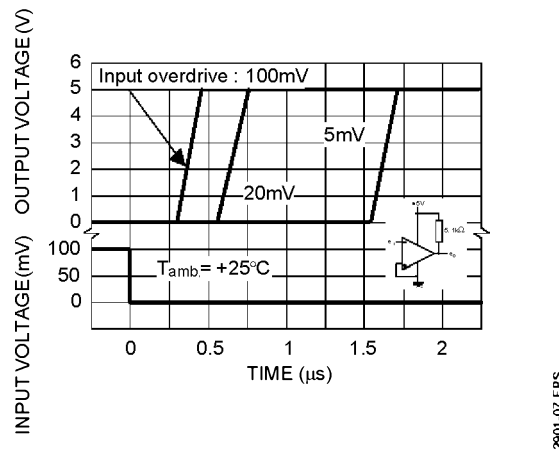
OUTPUT SATURATION VOLTAGE
versus OUTPUT CURRENT



RESPONSE TIME FOR VARIOUS INPUT
OVERDRIVES - NEGATIVE TRANSITION

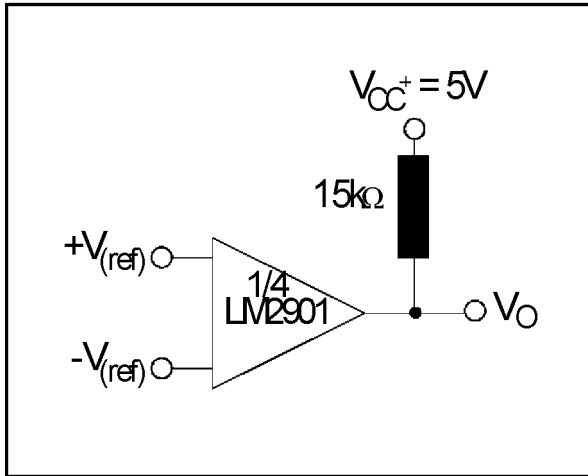


RESPONSE TIME FOR VARIOUS INPUT
OVERDRIVES - POSITIVE TRANSITION

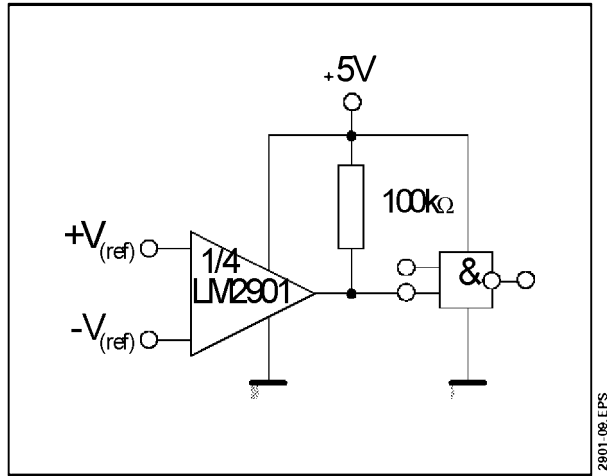


TYPICAL APPLICATIONS

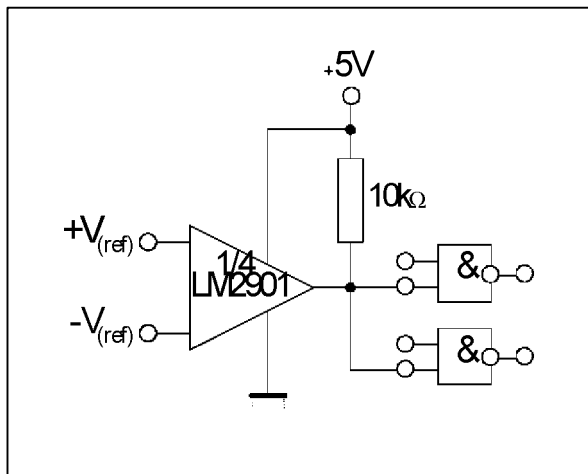
BASIC COMPARATOR



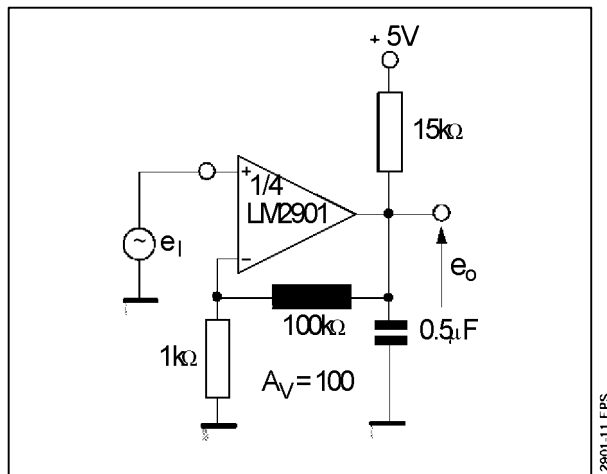
DRIVING CMOS



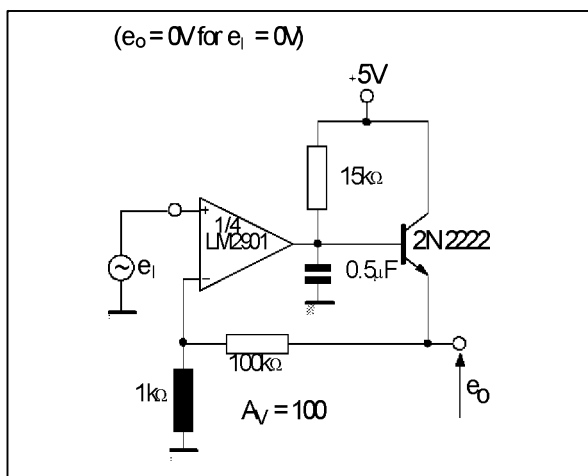
DRIVING TTL



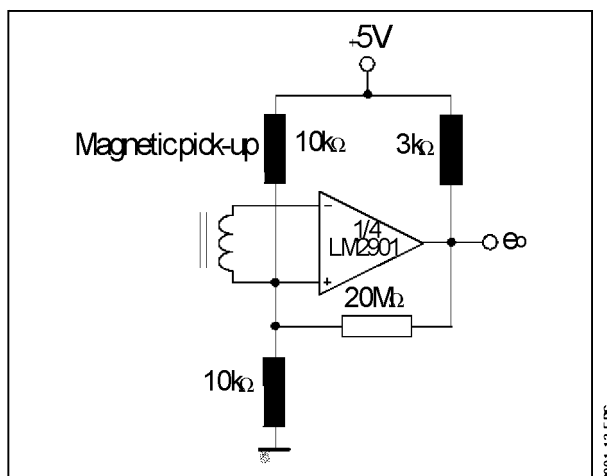
LOW FREQUENCY OP AMP



LOW FREQUENCY OP AMP

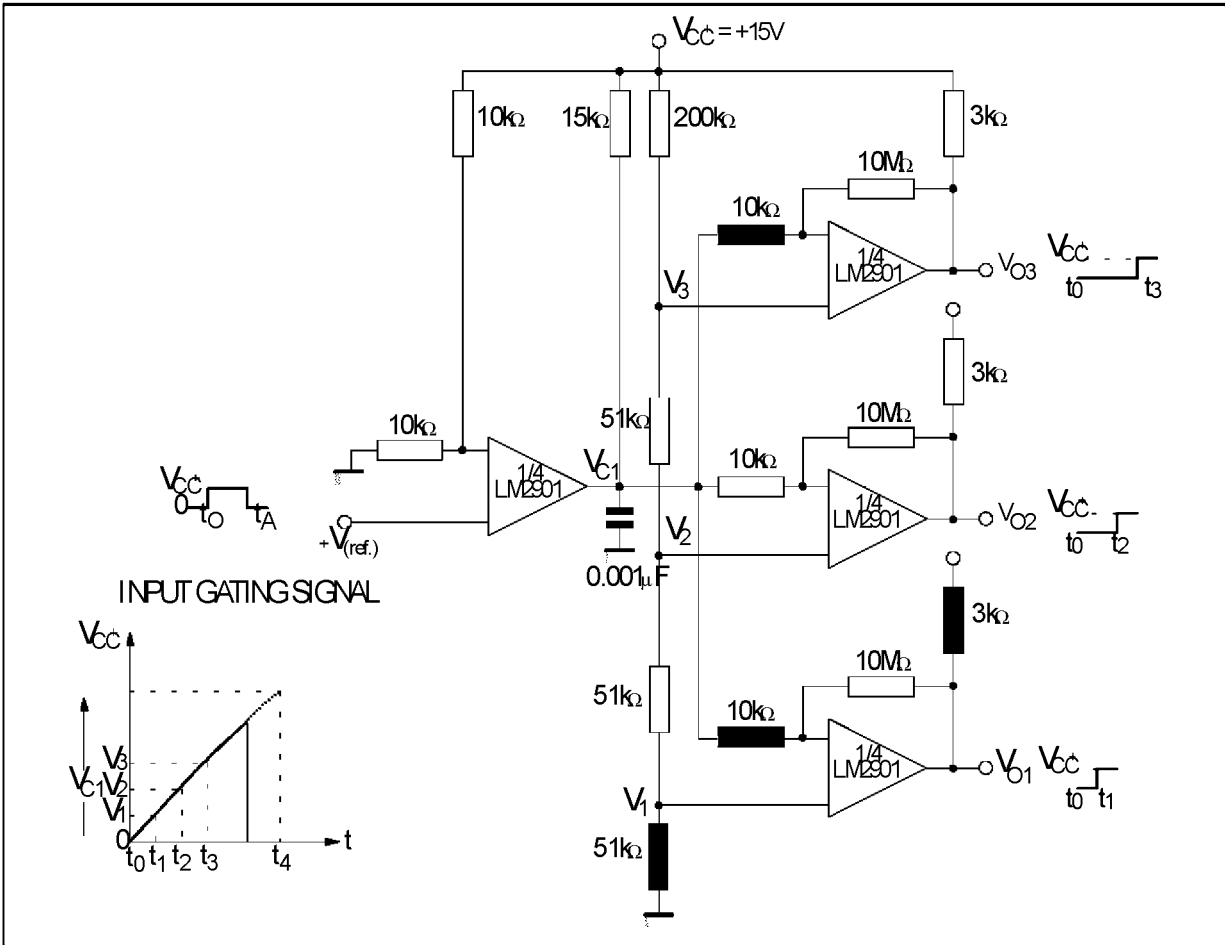


TRANSDUCER AMPLIFIER



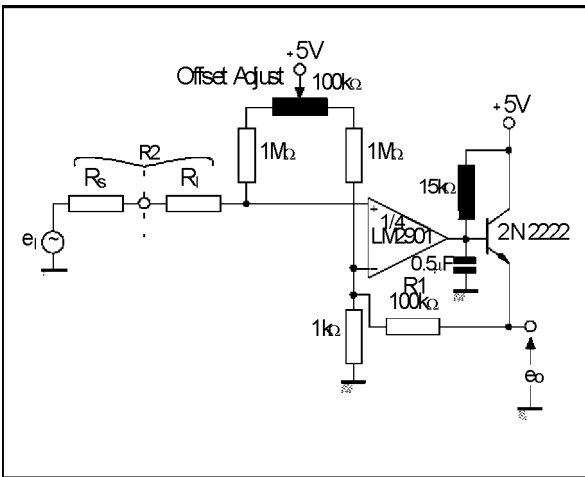
TYPICAL APPLICATIONS (continued)

TIME DELAY GENERATOR



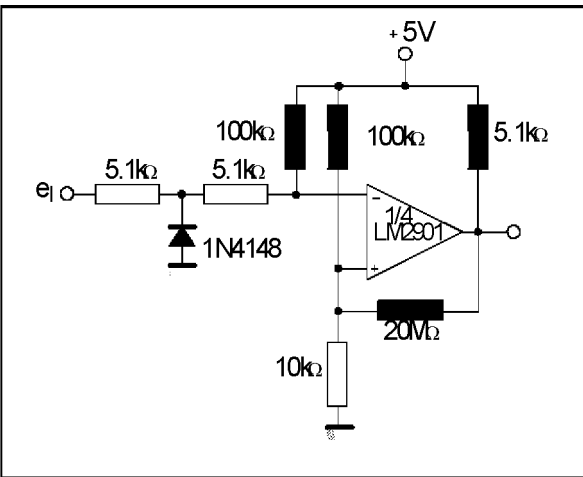
2901-14.EPS

LOW FREQUENCY OP AMP WITH OFFSET ADJUST



2901-15.EPS

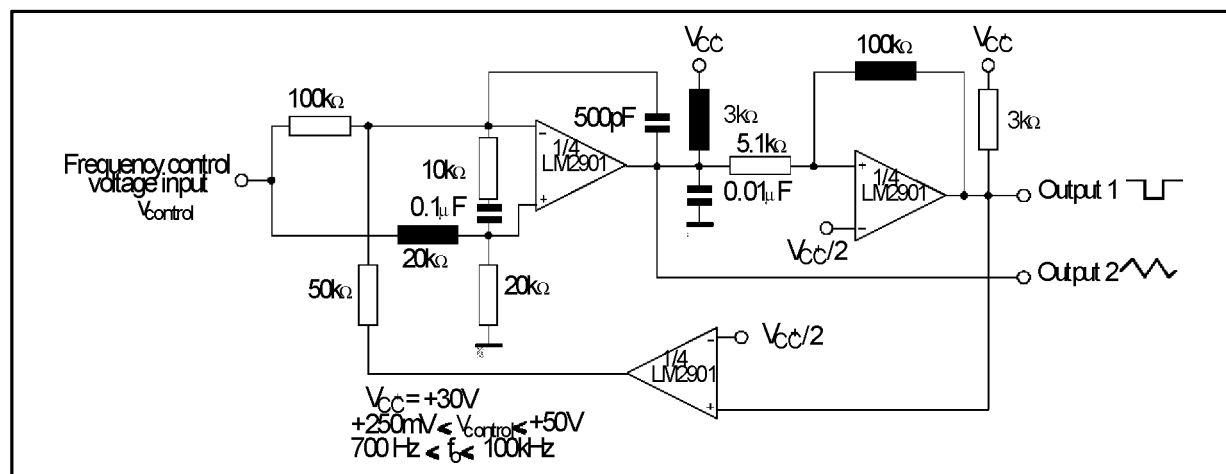
ZERO CROSSING DETECTOR (single power supply)



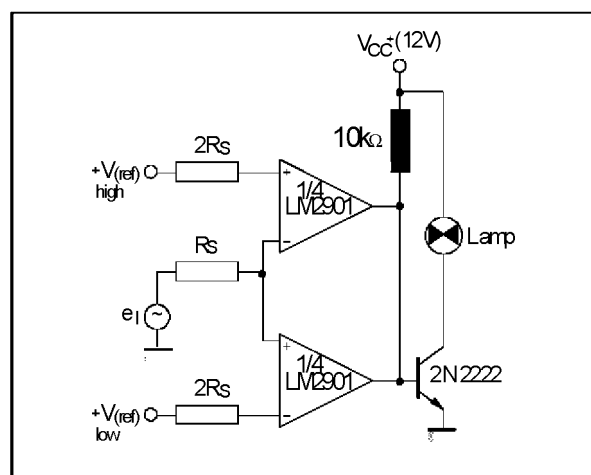
2901-16.EPS

TYPICAL APPLICATIONS (continued)

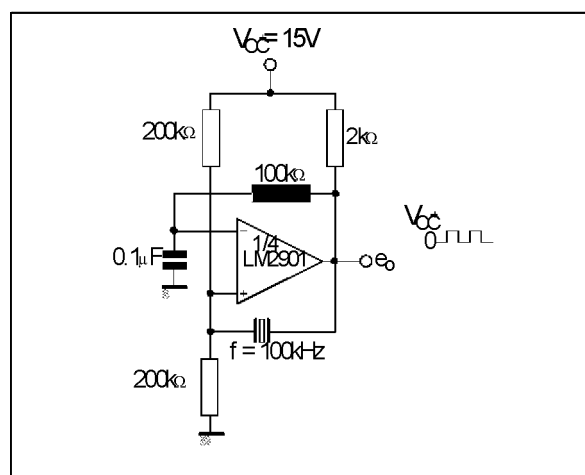
TWO-DECADE HIGH-FREQUENCY VCO



LIMIT COMPARATOR

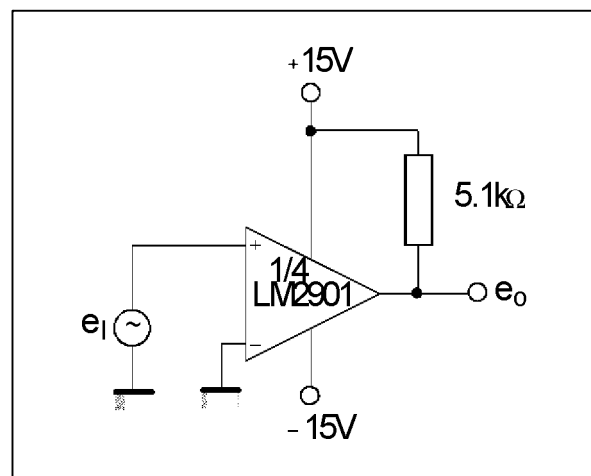


CRYSTAL CONTROLLED OSCILLATOR

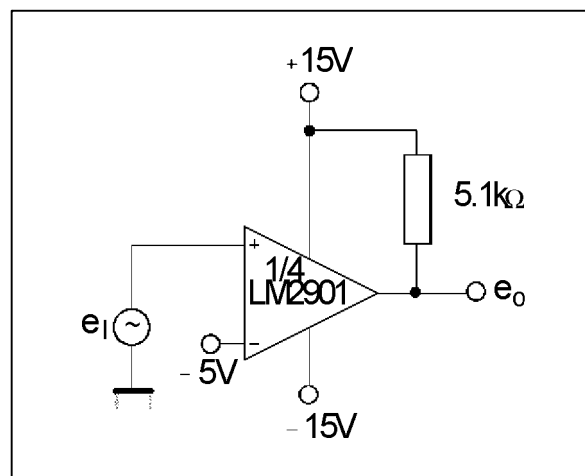


SPLIT-SUPPLY APPLICATIONS

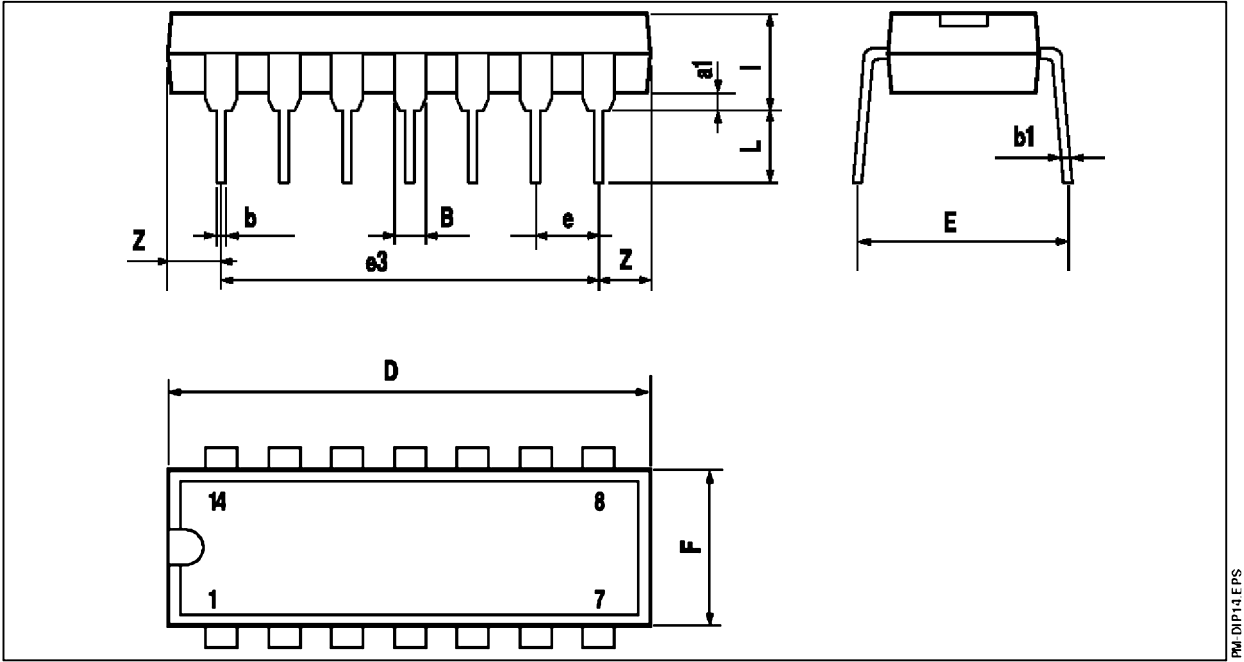
ZERO CROSSING DETECTOR



COMPARATOR WITH A NEGATIVE REFERENCE

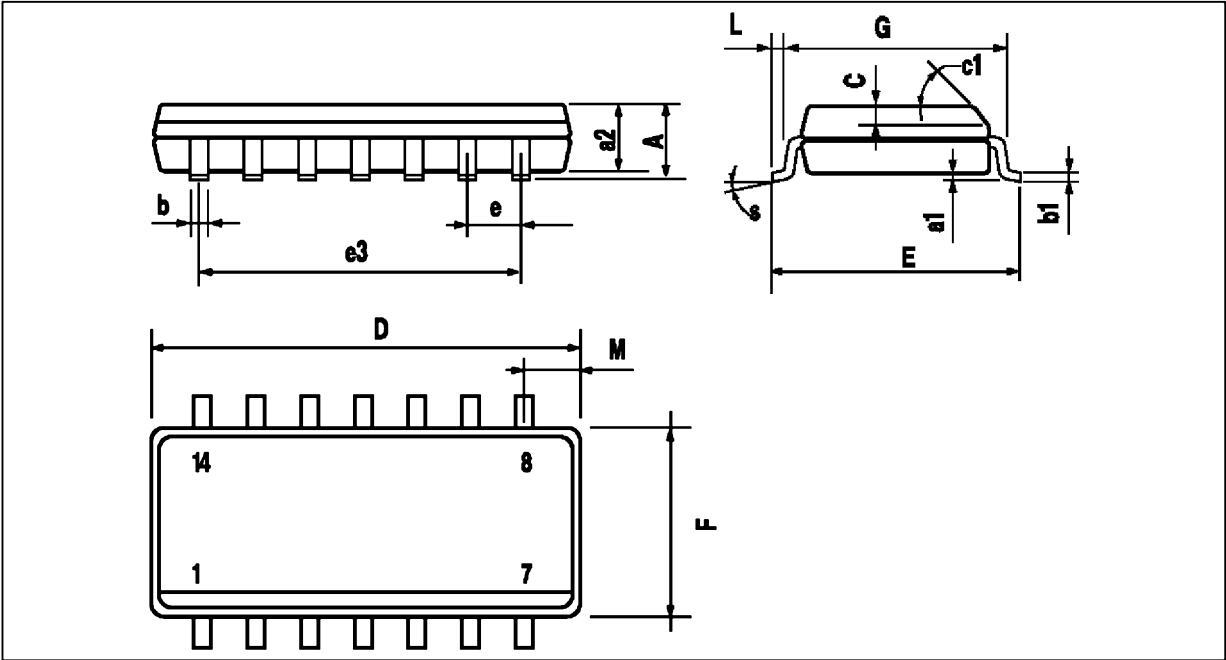


PACKAGE MECHANICAL DATA
14 PINS - PLASTIC DIP OR CerdIP



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

PACKAGE MECHANICAL DATA
14 PINS - PLASTIC MICROPACKAGE (SO)



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.334
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
M			0.68			0.027
S	8° (max.)					

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